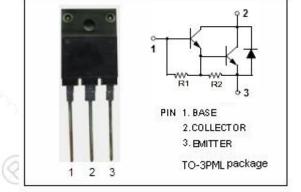


isc Silicon NPN Darlington Power Transistor

2SD2196

DESCRIPTION

- · High DC Current Gain
 - : h_{FE}= 1500(Min.)@ I_C= 10A, V_{CE}= 3V
- · High Collector-Emitter Sustaining Voltage-
 - : $V_{CEO(SUS)} = 200V(Min)$
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



APPLICATIONS

• Designed for general purpose amplifier applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	200	V	
V _{CEO}	Collector-Emitter Voltage	200	V	
V _{EBO}	Emitter-Base Voltage	7	٧^	
Ic	Collector Current-Continuous	15	Α	
Ісм	Collector Current-Peak	22	А	
I _B	Base Current- Continuous	1	А	
I _{BM}	Base Current- Peak	2	А	
Pc	Collector Power Dissipation @T _C =25°C 65		W	
T _j	Junction Temperature	nction Temperature 150		
T _{stg}	Storage Temperature Range	-55~150	°C	

mm MIN MAX 19.90 20.10 15.75 16.10 5.50 5.70 0.90 3.30 3.50 2.90 3.20 5.90 Н 6.10 0.595 0.70 21.10 1.90 10.80 11.00 4.90

THERMAL CHARACTERISTICS

SYMBOL PARAMETER		MAX	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	1.92	°C/W

Z

3.75 3.20 9.90

4.20 1.90 10.10

4.90

isc Silicon NPN Darlington Power Transistor

2SD2196

ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

16-25 C unless otherwise specified									
SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT			
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 10A, I _B = 30mA			1.5	V			
V _{BE} (sat)	Base-Emitter Saturation Voltage	I _C = 10A, I _B = 30mA			2.0	V			
I _{CBO}	Collector Cutoff current	V _{CB} = 200V, I _E = 0			0.1	mA			
I _{CEO}	Collector Cutoff current	V _{CE} = 200V, I _B = 0	84.		0.1	mA			
ІЕВО	Emitter Cutoff Current	V _{EB} = 7V; I _C = 0			5	mA			
f _T	Current-Gain—Bandwidth Product	I _C = 1.5A; V _{CE} = 10V	8	20		MHz			
h _{FE}	DC Current Gain	I _C = 10A; V _{CE} = 3V	1500	*>	30000				
Switching Times									
ton	Turn-On Time	200			2	μS			
t _{stg}	Storage Time	I_{C} = 10A, I_{B1} = I_{B2} = 30mA; R _L = 3 Ω ; V_{BB2} = 4V			12	μS			
t _f	Fall Time				5	μS			

Notice:

ISC reserves the rights to make changes of the content herein the datasheet at any time without notification. The information contained herein is presented only as a guide for the applications of our products.

ISC products are intended for usage in general electronic equipment. The products are not designed for use in equipment which require specialized quality and/or reliability, or in equipment which could have applications in hazardous environments, aerospace industry, or medical field. Please contact us if you intend our products to be used in these special applications.

ISC makes no warranty or guarantee regarding the suitability of its products for any particular purpose, nor does ISC assume any liability arising from the application or use of any products, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.